

N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A) ^{a, e}	Q _g (Typ.)			
60	0.0018 at V _{GS} = 10 V	180	68 nC			
60	0.0028 at V _{GS} = 4.5 V	100	00110			

FEATURES

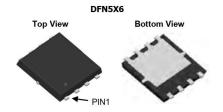
- **DT-Trench Power MOSFET**
- 100 % $\rm R_{\rm g}$ and UIS Tested
- AEC-Q101 Qualified for **Automotive Applications**

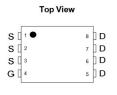


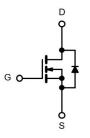
COMPLIANT

APPLICATIONS

- Notebook PC Core
- VRM/POL







N-Channel MOSFET

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage	V _{DS}	60	V		
Gate-Source Voltage	V_{GS}	± 20			
	T _C = 25 °C		180 ^{a, e}		
Continuous Drain Current (T _{.I} = 175 °C)	T _C = 70 °C		160 ^e		
Continuous Drain Current (1) = 173 C)	T _A = 25 °C	I _D	29 ^{b, c}	A	
	T _A = 70 °C		24 ^{b, c}	7 ^	
Pulsed Drain Current		I _{DM}	720		
Avalanche Current Pulse	L = 0.1 mH	I _{AS}	175		
Single Pulse Avalanche Energy	L = 0.1 IIII	E _{AS}	650	mJ	
Continuous Source-Drain Diode Current	T _C = 25 °C	I _s	180 ^{a, e}	A	
Continuous Source-Drain Diode Current	T _A = 25 °C	'S	4.68 ^{b, c}		
	T _C = 25 °C		250 ^a	w	
Maximum Power Dissipation	T _C = 70 °C	P _D	175		
Maximum Fower Dissipation	T _A = 25 °C	' υ	7.5 ^{b, c}		
	T _A = 70 °C		5.3 ^{b, c}		
Operating Junction and Storage Temperature Ra	T _J , T _{stg}	- 55 to 175	°C		

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Typical	Maximum	Unit			
Maximum Junction-to-Ambient ^{b, d}	t ≤ 10 s	R _{thJA}	18	25	°C/W		
Maximum Junction-to-Case	Steady State	R _{thJC}	0.6	0.8	- C/VV		

Notes:

- a. Based on T_C = 25 °C. b. Surface mounted on 1" x 1" FR4 board.

- c. t = 10 s.
 d. Maximum under steady state conditions is 90 °C/W.
 e. Calculated based on maximum junction temperature.



Parameter	Symbol	Test Conditions	Min .	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60			V
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	In = 250 µA		35		ma\//0C
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	ι _D – 230 μΑ		- 5.5		mV/°C
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0		3.0	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zana Cata Valtana Duain Commant	I _{DSS}	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ
Zero Gate Voltage Drain Current		$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			10	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	180			Α
	В	$V_{GS} = 10 \text{ V}, I_D = 50 \text{ A}$		0.0018	0.0025	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 30 \text{ A}$		0.0028	0.0036	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, I_D = 50 \text{ A}$		150		S
Dynamic ^b						
Input Capacitance	C _{iss}			4500		
Output Capacitance	C _{oss}	V_{DS} = 48 V , V_{GS} = 0 V, f = 1 MHz		1050		pF
Reverse Transfer Capacitance	C _{rss}			89		
T. (10) (1)	Qg	V _{DS} = 48 V, V _{GS} = 10 V, I _D = 50 A		68		nC
Total Gate Charge				35		
Gate-Source Charge	Q _{gs}	V_{DS} = 48 V, V_{GS} = 4.5 V, I_{D} = 30 A		15		
Gate-Drain Charge	Q _{gd}			14		
Gate Resistance	Rg	f = 1 MHz			3.5	Ω
Turn-On Delay Time	t _{d(on)}			17	22	
Rise Time	t _r	V_{DD} = 48 V, R_L = 0.555 Ω		11	15	ns
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 50$ A, V_{GEN} = 10 V, R_g = 1 Ω		25	45	
Fall Time	t _f			4	8	
Turn-On Delay Time	t _{d(on)}			8	13	
Rise Time	t _r	V_{DD} = 48 V, R_L = 0.625 Ω		62	75	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong 30$ A, V_{GEN} = 4.5 V, R_g = 1 Ω		22	43	
Fall Time	t _f			10	15	
Drain-Source Body Diode Characteristic	s					
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			180	۸
Pulse Diode Forward Current ^a	I _{SM}				720	A
Body Diode Voltage	V _{SD}	I _S = 30 A		0.8	1.2	V
Body Diode Reverse Recovery Time	t _{rr}			55	78	ns
Body Diode Reverse Recovery Charge Q		I _F = 20 A, di/dt = 100 A/μs, T _J = 25 °C		103	172	nC
Reverse Recovery Fall Time	ta	1 _F - 20 Λ, αι/αι - 100 Α/μs, 1 _J - 25 C		27		ns
Reverse Recovery Rise Time	t _b			25		

Notes:

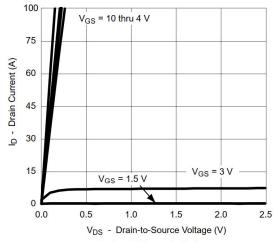
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

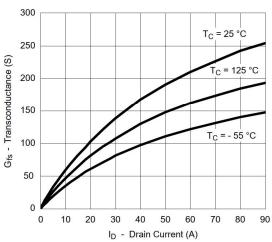
b. Guaranteed by design, not subject to production testing.



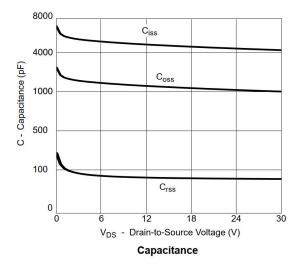
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

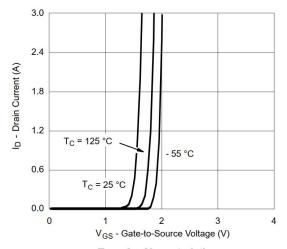


Output Characteristics

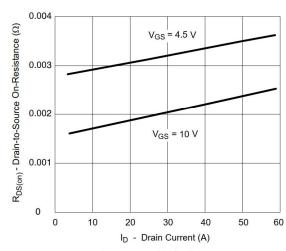


Transconductance

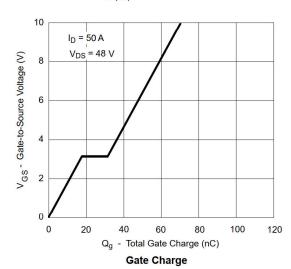




Transfer Characteristics



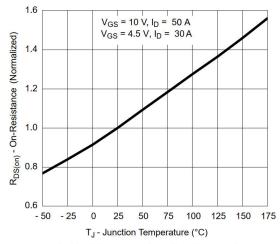
R_{DS(on)} vs. Drain Current



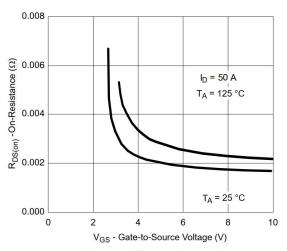
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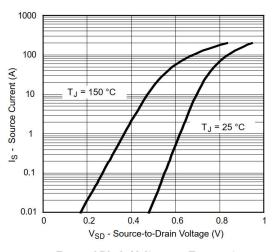
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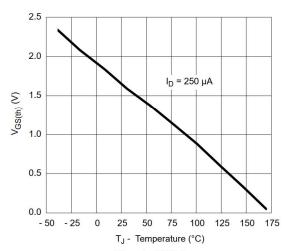
On-Resistance vs. Junction Temperature



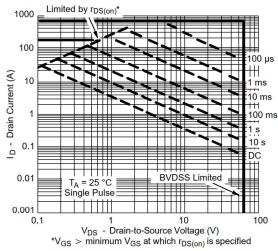
 $R_{DS(on)}$ vs. V_{GS} vs. Temperature



Forward Diode Voltage vs. Temperature



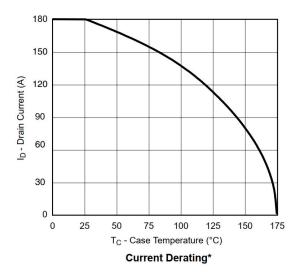
Threshold Voltage

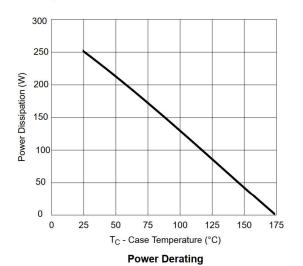


Safe Operating Area, Junction-to-Ambient

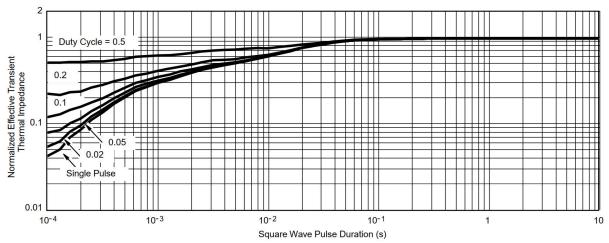


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





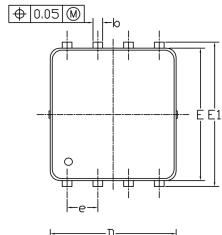
* The power dissipation P_D is based on $T_{J(max)}$ = 175 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

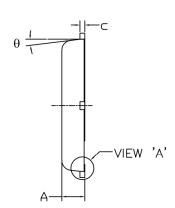


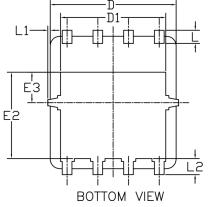
Normalized Thermal Transient Impedance, Junction-to-Case

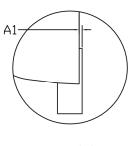


DFN5x6_8L_EP1_P PACKAGE OUTLIN



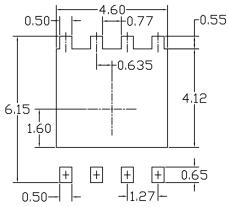






<u>VIEW 'A'</u> (SCALE 5:1)

RECOMMENDED LAND PATTERN



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES			
3 I WIBOLS	MIN	NOM	MAX	MIN	NOM	MAX	
A	0.85	1.00	1. 20	0.033	0.039	0.047	
A1	0.00		0.05	0.000		0.002	
b	0.30	0.40	0.50	0.012	0.016	0.020	
С	0.15	0. 20	0. 25	0.006	0.008	0.010	
D	5. 10	5. 25	5. 40	0. 201	0. 207	0. 213	
D1	4. 25	4. 35	4. 45	0. 167	0. 171	0. 175	
Е	5. 45	5. 60	5. 75	0. 215	0. 221	0. 226	
E1	5. 95	6. 10	6. 25	0. 234	0. 240	0. 246	
E2	3. 525	3.625	3. 725	0.139	0.143	0.147	
E3	1. 175	1. 275	1. 375	0.046	0.050	0.054	
e	1. 27 BSC			0.050 BSC			
L	0.45	0. 55	0.65	0.018	0.022	0.026	
L1	0		0.15	0		0.006	
L2	0.68 REF			0.027 REF			
θ	0°		10°	0°		10°	

NOTE

UNIT: mm

- 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS. MOLD FLASH AT THE NON-LEAD SIDES SHOULD BE LESS THAN 6 MILS EACH.
- 2. CONTROLLING DIMENSION IS MILLIMETER. CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.





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